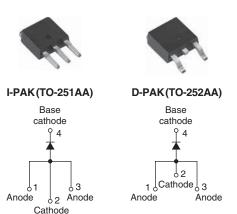


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Vishay Semiconductors

RoHS

# High Performance Generation 5.0 Schottky Rectifier, 10 A



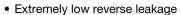
VS-10WT10FN

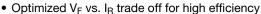
PRODUCT SUMMARY				
Package	I-PAK (TO-251AA),			
Fackage	D-PAK (TO-252AA)			
I <sub>F(AV)</sub>	10 A			
$V_{R}$	100 V			
V <sub>F</sub> at I <sub>F</sub>	0.66 V			
I <sub>RM</sub> max.	4 mA at 125 °C			
T <sub>J</sub> max.	175 °C			
Diode variation	Single die			
E <sub>AS</sub>	54 mJ			

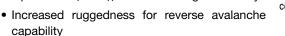
VS-10UT10

#### **FEATURES**

- 175 °C high performance Schottky diode
- Very low forward voltage drop







- RBSOA available
- Negligible switching losses
- Submicron trench technology
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47

### **APPLICATIONS**

- High efficiency SMPS
- High frequency switching
- · Output rectification
- Reverse battery protection
- Freewheeling
- DC/DC systems
- Increased power density systems

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
V <sub>RRM</sub>		100	V		
V <sub>F</sub>	10 Apk, T <sub>J</sub> = 125 °C (typical)	0.615	V		
T <sub>J</sub>	Range	- 55 to 175	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VS-10UT10 VS-10WT10FN	UNITS
Maximum DC reverse voltage	$V_{R}$	T <sub>J</sub> = 25 °C	100	V

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 159 °C, rectangular waveform		10	Α
Maximum peak one cycle non-repetitive surge current	I <sub>FSM</sub>	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied <sup>(1)</sup>	610	А
		10 ms sine or 6 ms rect. pulse		110	
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 3 A, L = 12 mH		54	mJ
Repetitive avalanche current	I <sub>AR</sub>	Limited by frequency of operation and time pulse duration so that $T_J < T_J$ max. $I_{AS}$ at $T_J$ max. as a function of time pulse (see fig. 8)		I <sub>AS</sub> at T <sub>J</sub> max.	А

#### Note

(1) Measured connecting 2 anode pins

Revision: 02-Nov-11 Document Number: 94647



ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Forward voltage drop	V <sub>FM</sub> <sup>(1)(2)</sup>	5 A		0.630	-	- V
		10 A	T <sub>J</sub> = 25 °C	0.735	0.810	
		20 A		0.840	0.890	
		5 A	T <sub>J</sub> = 125 °C	0.530	-	
		10 A		0.615	0.660	
		20 A		0.730	0.770	
Reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	V <sub>R</sub> = Rated V <sub>R</sub>	-	50	μΑ
		T <sub>J</sub> = 125 °C		-	4	mA
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal range 100 kHz to 1 MHz), 25 °C		400	-	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body		8.0	-	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		-	10 000	V/µs

#### Notes

- $^{(1)}\,$  Pulse width < 300 µs, duty cycle < 2 %
- (2) Only 1 anode pin connected

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to 175	°C
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	2	°C/W
Typical thermal resistance, case to heatsink	R <sub>thCS</sub>		0.3	C/VV
Approximate weight			0.3	g
Approximate weight			0.01	OZ.
Marking device		Case style I-PAK	10U	T10
		Case style D-PAK	10WT	10FN

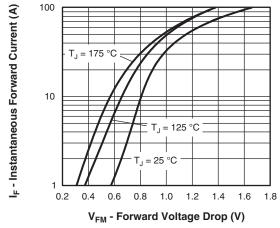


Fig. 1 - Maximum Forward Voltage Drop Characteristics

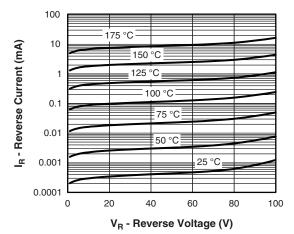


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

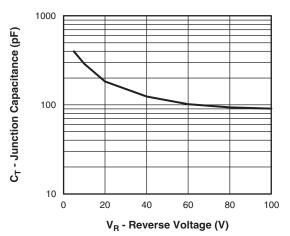


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

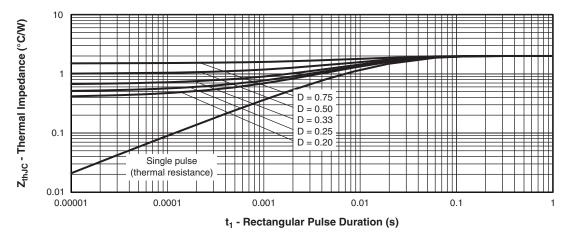


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

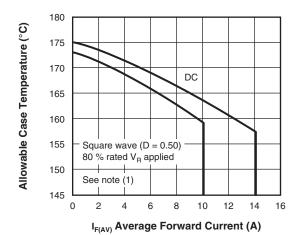


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

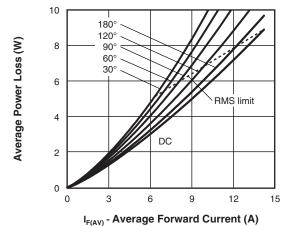
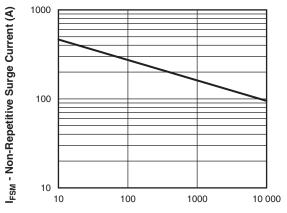


Fig. 6 - Forward Power Loss Characteristics



t<sub>p</sub> - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

#### Note

 $^{(1)}$  Formula used: T<sub>C</sub> = T<sub>J</sub> - (Pd + Pd<sub>REV</sub>) x R<sub>thJC</sub>; Pd = Forward power loss = I<sub>F(AV)</sub> x V<sub>FM</sub> at (I<sub>F(AV)</sub>/D) (see fig. 6); Pd<sub>REV</sub> = Inverse power loss = V<sub>R1</sub> x I<sub>R</sub> (1 - D); I<sub>R</sub> at V<sub>R1</sub> = 80 % rated V<sub>R</sub>

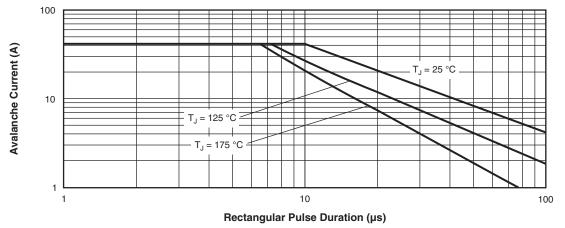


Fig. 8 - Reverse Bias Safe Operating Area (Avalanche Current vs. Rectangular Pulse Duration)

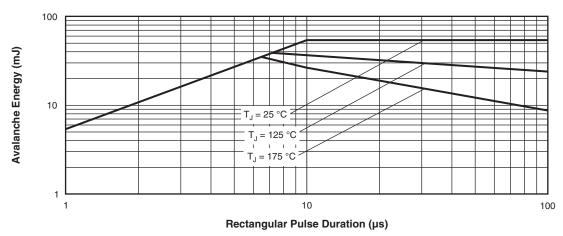
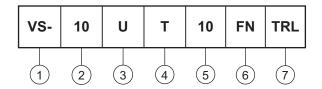


Fig. 9 - Reverse Bias Safe Operating Area (Avalanche Energy vs. Rectangular Pulse Duration)



### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

Current rating (10 A)

3 - Package:

• U = I-PAK

•W=D-PAK

4 - T = Trench

5 - Voltage code (100 V)

6 - TO-252AA (D-PAK)

7 - D-PAK, I-PAK:

None = Tube (75 pieces)

D-PAK only:

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

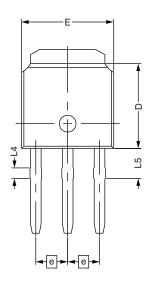
• TRR = Tape and reel (right oriented)

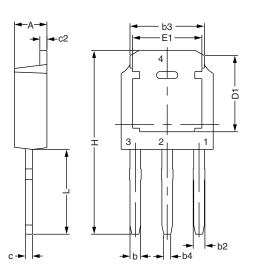
LINKS TO RELATED DOCUMENTS				
Dimensions	I-PAK (TO-251AA)	www.vishay.com/doc?95024		
Differsions	D-PAK (TO-252AA)	www.vishay.com/doc?95448		
Part marking information	I-PAK (TO-251AA)	www.vishay.com/doc?95025		
	D-PAK (TO-252AA)	www.vishay.com/doc?95059		
Packaging information		www.vishay.com/doc?95033		
SPICE model		www.vishay.com/doc?95026		



### I-PAK - S

### **DIMENSIONS FOR I-PAK - S** in millimeters





SYMBOL	DIMENSIONAL REQUIREMENTS			
STMBOL	MIN.	NOM.	MAX.	
E	6.40	6.60	6.70	
L	3.98	4.13	4.28	
L4	0.66	0.76	0.86	
L5	1.96	2.16	2.36	
D	6.00	6.10	6.20	
Н	11.05	11.25	11.45	
b	0.64	0.76	0.88	
b2	0.77	0.84	1.14	
b3	5.21	5.34	5.46	
b4	0.41	0.51	0.61	
е	2.286 BSC			
Α	2.20	2.30	2.38	
С	0.40	0.50	0.60	
c2	0.40	0.50	0.60	
D1	5.30	-	-	
E1	4.40	-	-	

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Revision: 02-Oct-12 Document Number: 91000